



Nikolai Wolff (Autor)

Wideband GaN Microwave Power Amplifiers with Class-G Supply Modulation

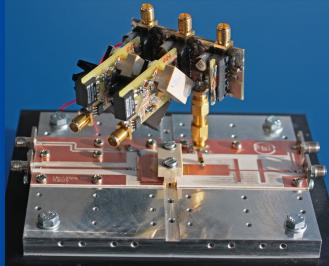


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für Höchstfrequenztechnik

Wideband GaN Microwave Power
Amplifiers with Class-G Supply
Modulation



Innovationen mit Mikrowellen & Licht

Nikolai Wolff

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